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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/767,684	01/29/2004	Ashraf W. Lotfi	ENP-004	ENP-004 7088	
25962 7.	590 03/24/2005		EXAMINER		
SLATER & MATSIL, L.L.P. 17950 PRESTON RD, SUITE 1000			ERDEM, FAZLI		
DALLAS, TX 75252-5793			ART UNIT	PAPER NUMBER	
			2826		
			DATE MAILED: 03/24/2005	DATE MAILED: 03/24/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)				
Office Antique Commence		10/767,684	LOTFI ET AL.				
	Office Action Summary	Examiner	Art Unit				
		Fazli Erdem	2826				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
THE - Exte after - If the - If NC - Failt Any	IORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. In a period for reply specified above is less than thirty (30) days, a repular point of the provision of the provi	136(a). In no event, however, may a reply be timely within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from a, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
Status							
1)[🖂	Responsive to communication(s) filed on 29 J	lanuary 2004.					
		s action is non-final.					
3)[<u> </u>						
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposit	ion of Claims						
4)⊠	4)⊠ Claim(s) <u>1-7 and 15-25</u> is/are pending in the application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)□	5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) <u>1,3,6,7,15-21,24 and 25</u> is/are rejected.						
8)[_]	Claim(s) are subject to restriction and/o	or election requirement.					
Applicati	ion Papers						
9)☐ The specification is objected to by the Examiner.							
10)[10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority (ınder 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No.							
 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage 							
	application from the International Burea		u III tilis National Stage				
* See the attached detailed Office action for a list of the certified copies not received.							
	•						
Attachment(s) 1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)							
2) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Summary (Paper No(s)/Mail Da	P10-413) le				
3) 🔯 Inforr	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) r No(s)/Mail Date <u>08/09/04</u> .		atent Application (PTO-152)				

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DETAILED ACTION

Allowable Subject Matter

1. Claims 2, 4, 5, 22 and 23 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1 and 3 rejected under 35 U.S.C. 102(b) as being anticipated by Mihnea et al. (6,384,447).

Regarding Claims 1 and 3, Mihnea et al. disclose a source/drain regions 112 and 115 including a lightly doped region 133 and heavily doped region 136 adjacent to each other, an oppositely doped well region 128 under and within the channel region 162, , doped region 139 located between the heavily doped region 136 and oppositely doped well region 128 having a doping concentration profile less than a doping concentration profile of the heavily doped region.

Regarding Claim 3, substrate 106 has epitaxial layers.

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 6,7, 15-21, 24 and 25 rejected under 35 U.S.C. 103(a) as being unpatentable over Mihnea et al. (6,384,447) in view of Cai et al. (2004/0227190).

Regarding Claims 6,7, 15-21, 24 and 25, Mihnea et al. disclose a source/drain regions 112 and 115 including a lightly doped region 133 and heavily doped region 136 adjacent to each other, an oppositely doped well region 128 under and within the channel region 162, , doped region 139 located between the heavily doped region 136 and oppositely doped well region 128 having a doping concentration profile less than a doping concentration profile of the heavily doped region. Mihnea et al. Fail to disclose the required LDMOS and sidewall/spacers. However, Cai et al. disclose an ESD protection for semiconductor products where in Fig. 1, LDMOS structure has sidewall spacers 44.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required LDMOS and sidewall spacers in Mihnea et al. as taught by Cai. et al. in order to have semiconductor device with increased performance and reliability.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's

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supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE

March 18, 2005

NAPHAN J. FLYNN SUPERVISORY PATENT EXAMINED

TECHNOLOGY CENTER 2800